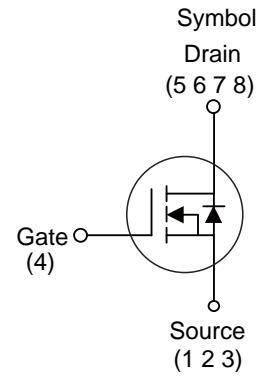


■ PRODUCT CHARACTERISTICS

V <sub>DSS</sub>	20V
R <sub>DS(ON)Typ</sub> (@V <sub>GS</sub> =4.5V)	5.6mΩ
R <sub>DS(ON)Typ</sub> (@V <sub>GS</sub> =2.5V)	6.8mΩ
I <sub>D</sub>	60A

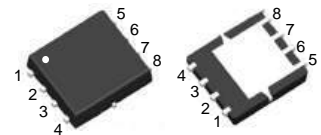


■ APPLICATIONS

- \* Electronic lamp ballasts based on half bridge
- \* Load Switching, Quick/Wireless Charge.
- \* Motor Driving

■ FEATURE

- \* Low Gate Charge
- \* Pb-Free Lead Plating



PDFN3X3

■ ORDER INFORMATION

Order Codes		Package	Packing
Halogen-Free	Halogen		
N/A	MOT2176J	PDFN3X3	5000 pieces/Reel

■ ABSOLUTE MAXIMUM RATINGS(T<sub>A</sub>=25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V <sub>DSS</sub>	20	V
Gate-Source Voltage	V <sub>GSS</sub>	±12	V
Drain Current Continuous(@V <sub>GS</sub> =4.5V, T <sub>A</sub> =25°C)	I <sub>D</sub>	60	A
Drain Current Continuous(@V <sub>GS</sub> =4.5V, T <sub>A</sub> =100°C)	I <sub>D</sub>	42	A
Drain Current Pulsed	I <sub>DM</sub>	240	A
Avalanche Energy*	E <sub>AS</sub>	95	mJ
Power Dissipation	P <sub>D</sub>	40	W
Junction Temperature	T <sub>J</sub>	+150	°C
Storage Temperature	T <sub>STG</sub>	-55~ +150	°C

■ THERMAL CHARACTERISTICS

Parameter	Symbol	Typ	Unit
Junction to Case	R <sub>thJC</sub>	3.13	°C/W

Note: \* EAS condition: T<sub>J</sub>=25°C, V<sub>DD</sub>=12V, V<sub>G</sub>=10V, L=0.5mH, R<sub>g</sub>=25Ω

**■ ELECTRICAL CHARACTERISTICS** ( $T_C=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off characteristics						
Drain to Source Breakdown Voltage	$V_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Drain to Source Leakage Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate to Source Forward Leakage	$I_{GSS}(F)$	$V_{GS}=+12V, V_{DS}=0V$	-	-	100	nA
Gate to Source Reverse Leakage	$I_{GSS}(R)$	$V_{GS}=-12V, V_{DS}=0V$	-	-	-100	nA
On characteristics						
Drain to Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=10A$	-	5.6	7	$m\Omega$
		$V_{GS}=2.5V, I_D=10A$	-	6.8	7.8	$m\Omega$
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.3	0.62	1.1	V
Dynamic characteristics						
Gate capacitance	$R_g$	$V_{GS}=0V, V_{DS}=0V, f=1.0MHz$	-	1.6	-	$\Omega$
Forward Transconductance	$g_{fs}$	$V_{DS}=10V, I_D=3A$	-	11	-	S
Input Capacitance	$C_{iss}$	$V_{DS}=12V, V_{GS}=0V$ $f=1.0MHz$	-	1200	-	pF
Output Capacitance	$C_{oss}$		-	152	-	pF
Reverse Transfer Capacitance	$C_{rss}$		-	148	-	pF
Resistive Switching Characteristics						
Turn-on Delay Time	$t_{d(ON)}$	$V_{GS}=4.5V, V_{DS}=10V,$ $I_D=20A, R_G=3\Omega$	-	6.4	-	ns
Rise Time	$t_r$		-	17.2	-	ns
Turn-off Delay Time	$t_{d(OFF)}$		-	29.6	-	ns
Fall Time	$t_f$		-	16.8	-	ns
Total Gate Charge	$Q_g$	$I_D=20A, V_{DS}=10V$ $V_{GS}=4.5V$	-	35	-	nC
Gate to Source Charge	$Q_{gs}$		-	3	-	nC
Gate to Drain("Miller") Charge	$Q_{gd}$		-	10	-	nC
Source-Drain Diode Characteristics						
Continuous Source Current(Body Diode)	$I_S$		-	-	60	A
Maximum Pulsed Current(Body Diode)	$I_{SM}$		-	-	240	A
Diode Forward Voltage	$V_{SD}$	$I_{SD}=1A, V_{GS}=0V$	-	0.72	1.2	V
Reverse Recovery Time	$t_{rr}$	$I_{SD}=20A, T_J=25^{\circ}\text{C}$	-	25	-	ns
Reverse Recovery Charge	$Q_{rr}$	$di/dt=100A/\mu s$	-	24	-	nC

■ TYPICAL CHARACTERISTICS

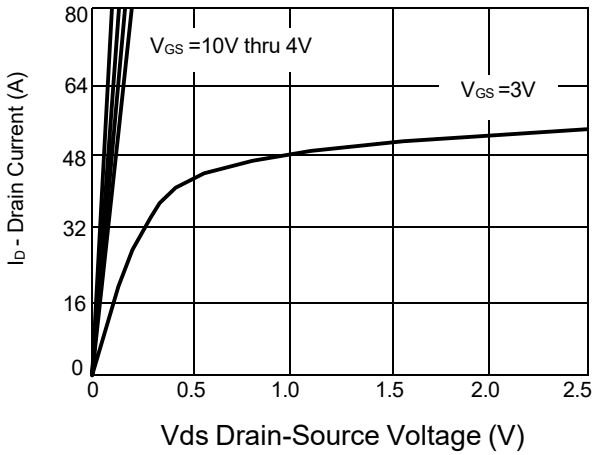


Figure 1: Output characteristics

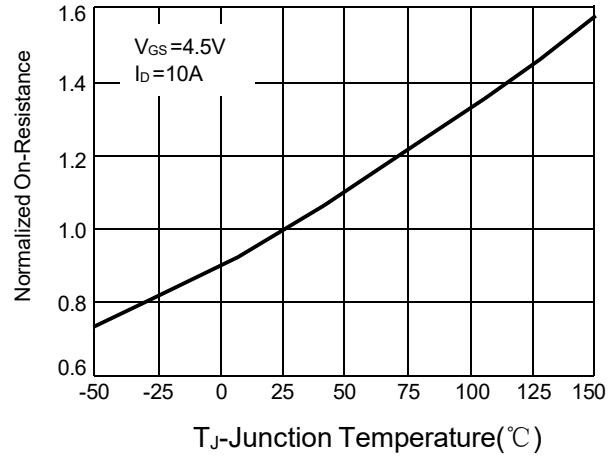


Figure 2:  $R_{dson}$ -junction temperature

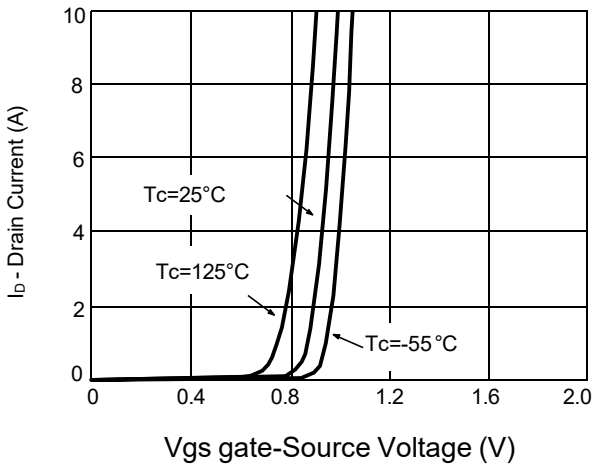


Figure 3: Transfer characteristics

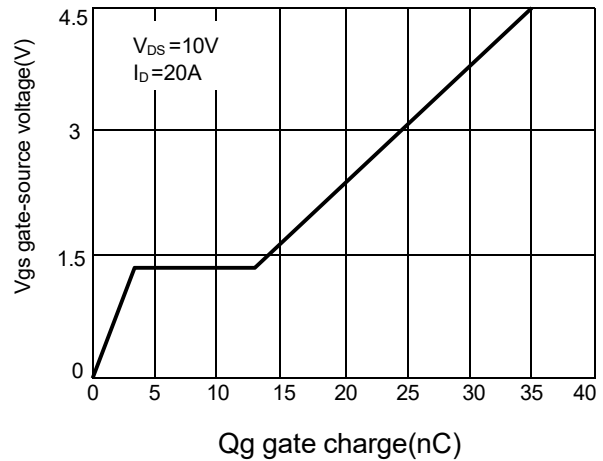


Figure 4: Gate charge

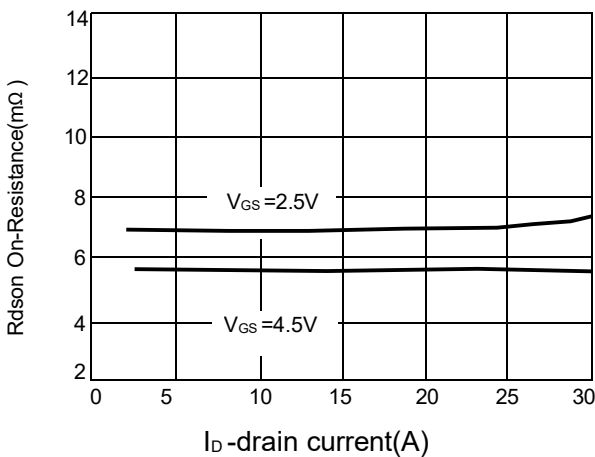


Figure 5:  $R_{dson}$ -drain current

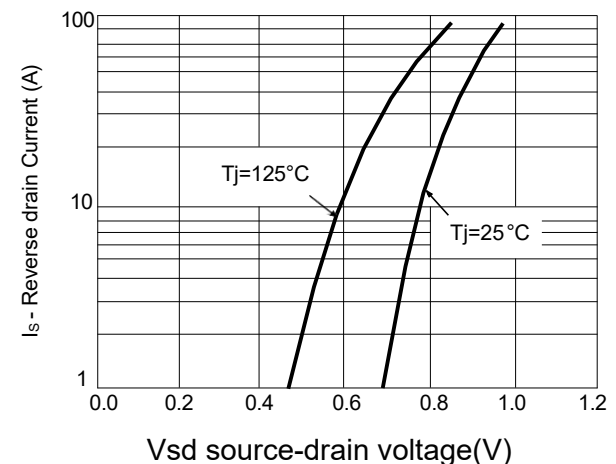


Figure 6: Source-drain diode forward

■ TYPICAL CHARACTERISTICS(Cont.)

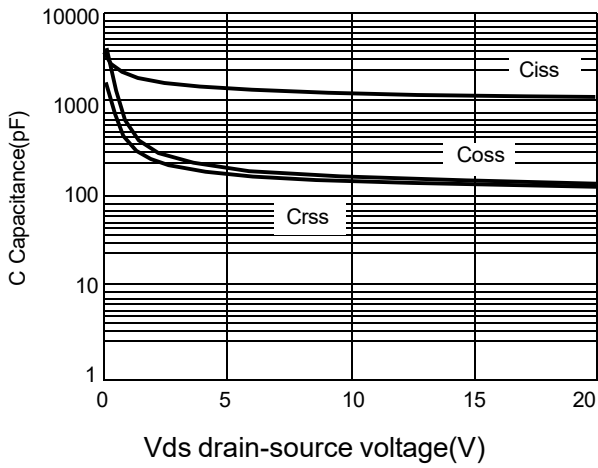


Figure 7: Capatitance de-rating

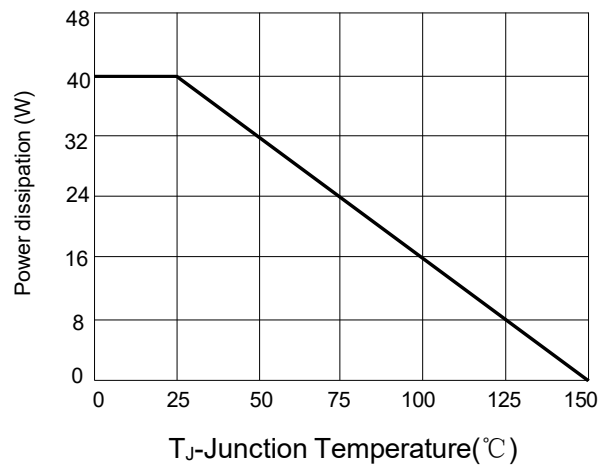


Figure 8: Power de-rating

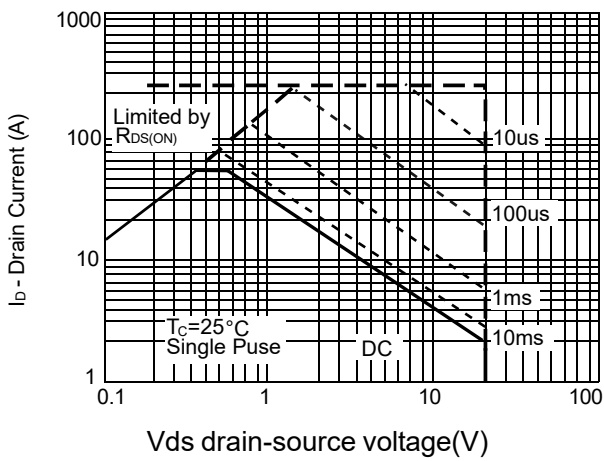


Figure 9: Safe operation area

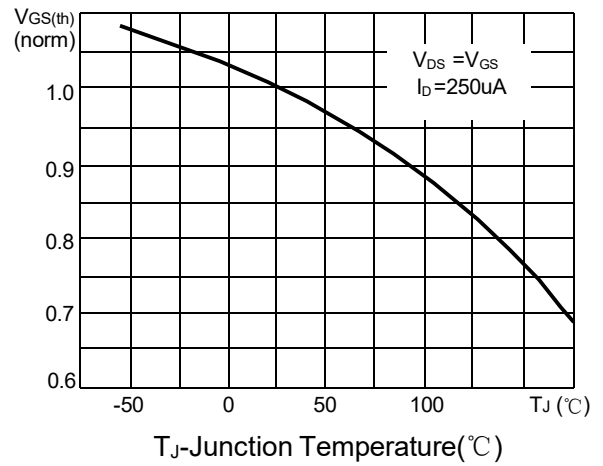
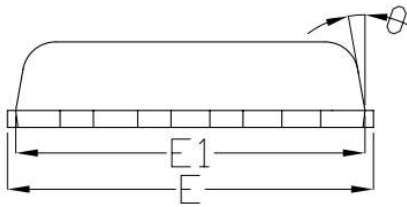
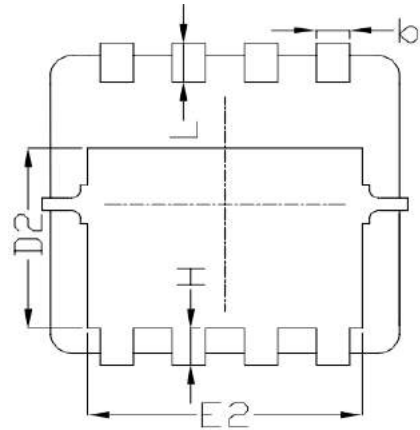
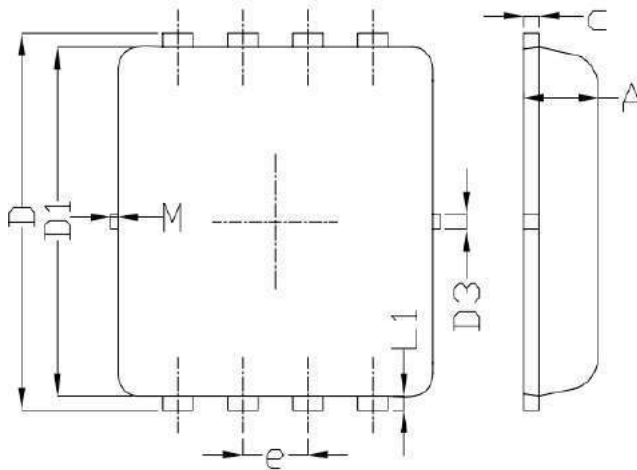
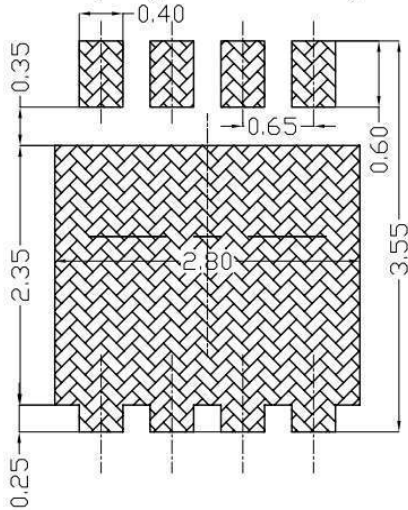


Figure 10:  $V_{GS(th)}$  vs junction temperature

■ PDFN3X3 PACKAGE OUTLINE DIMENSIONS



Land Pattern  
(Only for Reference)



SYMBOL	DIMENSIONAL REQOMTS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	---	0.13	---
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	---	0.13	---
θ	---	10°	12°
M	*	*	0.15
* Not specified			